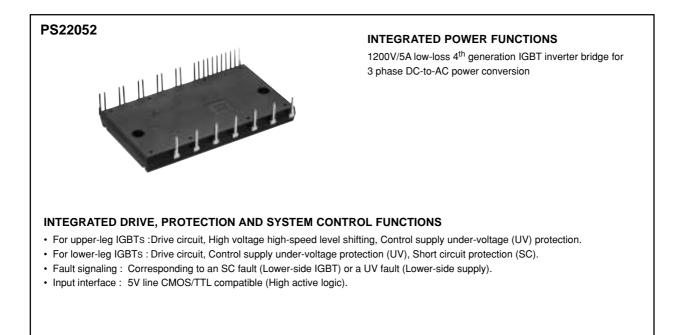
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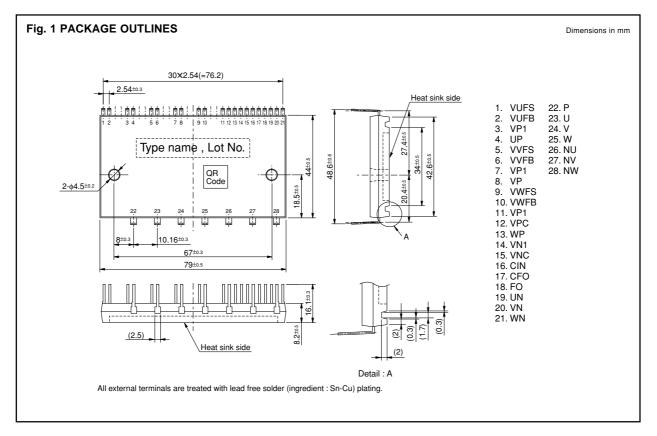
PS22052

TRANSFER-MOLD TYPE INSULATED TYPE



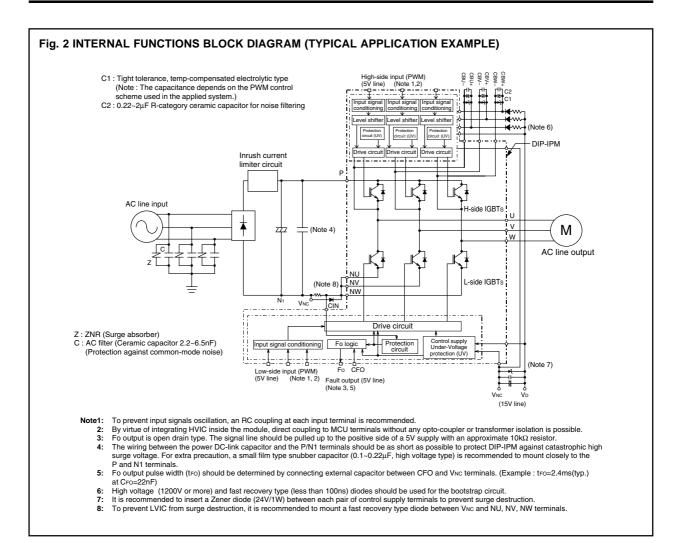
## APPLICATION

AC400V 0.2kW~0.4kW inverter drive for small power motor control.

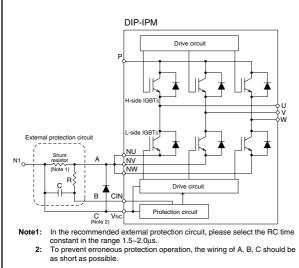


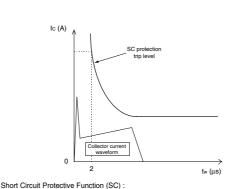


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#### Fig. 3 EXTERNAL PART OF THE DIP-IPM PROTECTION CIRCUIT





Short circuit Protective Function (SC): SC protection is achieved by sensing the L-side DC-Bus current (through the external shunt resistor) with a suitable filtering time (defined by the RC circuit). When the sensed shunt voltage exceeds the SC trip-level, all the L-side IGBTs are turned DEF and circuit sized (Circuit sense).

OFF and a fault signal (Fo) is output. Since the SC fault may be repetitive, it is recommended to stop the system and check the fault, when the Fo signal is received.



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### MAXIMUM RATINGS (Tj = 25°C, unless otherwise noted) INVERTER PART

| Symbol     | Parameter                          | Condition                    | Ratings    | Unit |
|------------|------------------------------------|------------------------------|------------|------|
| Vcc        | Supply voltage                     | Applied between P-NU, NV, NW | 900        | V    |
| VCC(surge) | Supply voltage (surge)             | Applied between P-NU, NV, NW | 1000       | V    |
| VCES       | Collector-emitter voltage          |                              | 1200       | V    |
| ±IC        | Each IGBT collector current        | Tc = 25°C                    | 5          | A    |
| ±Іср       | Each IGBT collector current (peak) | Tc = 25°C, less than 1ms     | 10         | A    |
| Pc         | Collector dissipation              | Tc = 25°C, per 1 chip        | 38.3       | W    |
| Tj         | Junction temperature               | (Note 1                      | ) —20~+125 | °C   |

Note 1 : The maximum junction temperature rating of the power chips integrated within the DIP-IPM is 150°C (@ Tc ≤ 100°C) however, to ensure safe operation of the DIP-IPM, the average junction temperature should be limited to T<sub>j(ave)</sub> ≤ 125°C (@ Tc ≤ 100°C).

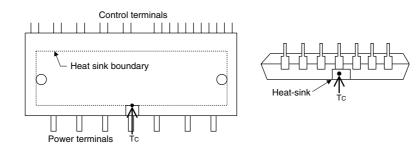
### **CONTROL (PROTECTION) PART**

| Symbol | Parameter                     | Condition  | Ratings     | Unit |
|--------|-------------------------------|--|-------------|------|
| Vd     | Control supply voltage        | Applied between VP1-VPC, VN1-VNC                   | 20          | V    |
| Vdb    | Control supply voltage        | Applied between VUFB-VUFS, VVFB-VVFS,<br>VWFB-VWFS | 20          | V    |
| VIN    | Input voltage                 | Applied between UP, VP, WP-VPC,<br>UN, VN, WN-VNC  | -0.5~VD+0.5 | V    |
| Vfo    | Fault output supply voltage   | Applied between FO-VNC                             | -0.5~VD+0.5 | V    |
| IFO    | Fault output current          | Sink current at Fo terminal                        | 1           | mA   |
| Vsc    | Current sensing input voltage | Applied between CIN-VNC                            | -0.5~VD+0.5 | V    |

### TOTAL SYSTEM

| Symbol    | Parameter  | Condition  | Ratings  | Unit |
|-----------|--|--|----------|------|
| VCC(PROT) | Self protection supply voltage limit (short circuit protection capability) | $V_D = 13.5 \sim 16.5 V$ , Inverter part<br>T <sub>j</sub> = 125°C, non-repetitive, less than 2 µs | 800      | V    |
| Тс        | Module case operation temperature  | (Note 2)   | -20~+100 | °C   |
| Tstg      | Storage temperature  |  | -40~+125 | °C   |
| Viso      | Isolation voltage  | 60Hz, Sinusoidal, AC 1 minute, connection<br>pins to heat-sink plate                               | 2500     | Vrms |

## Note 2 : TC MEASUREMENT POINT





## **TRANSFER-MOLD TYPE INSULATED TYPE**

### THERMAL RESISTANCE

| Symbol Parameter | Devenator                           | Condition  | Limits |      |       | Unit |
|------------------|-------------------------------------|--|--------|------|-------|------|
|                  | Condition                           |  | Тур.   | Max. |       |      |
| Rth(j-c)Q        | Junction to case thermal            | Inverter IGBT part (per 1/6 module)                | —      | —    | 2.61  | °C/W |
| Rth(j-c)F        | resistance                          | Inverter FWDi part (per 1/6 module)                | —      | —    | 3.18  | °C/W |
| Rth(c-f)         | Contact thermal resistance (Note 3) | Case to fin, (per 1 module) thermal grease applied | _      | _    | 0.047 | °C/W |

Note 3: Grease with good thermal conductivity and long-term endurance should be applied evenly with about +100µm~+200µm on the con-tacting surface of DIP-IPM and heat-sink.

#### ELECTRICAL CHARACTERISTICS (Tj = 25°C, unless otherwise noted) **INVERTER PART**

| Oursels al                   | Demension                 | Condition   |              |      | Limits |      |      |
|------------------------------|---------------------------|---|--------------|------|--------|------|------|
| Symbol                       | Parameter                 |   |              | Min. | Тур.   | Max. | Unit |
| Collector-emitter saturation |                           | VD = VDB = 15V  | Tj = 25°C    | —    | 2.7    | 3.4  |      |
| VCE(sat) Voltage             | VIN = 5V, IC = 5A         | Tj = 125°C  | —            | 2.5  | 3.2    | V    |      |
| VEC                          | FWDi forward voltage      | -IC = 5A, VIN = 0V  |              | —    | 2.4    | 2.9  | V    |
| ton                          |                           |   |              | 0.8  | 1.5    | 2.2  | μs   |
| trr                          |                           | $Vcc = 600V, VD = VDB = 15V$ $Ic = 5A, Tj = 125^{\circ}C, VIN = 0 \leftrightarrow 5V$ |              | —    | 0.2    | —    | μs   |
| tc(on)                       | Switching times           |   |              | —    | 0.4    | 0.7  | μs   |
| toff                         |                           | Inductive load (upper   | r-lower arm) | —    | 2.8    | 3.8  | μs   |
| tc(off)                      |                           |   |              | —    | 0.4    | 0.7  | μs   |
| ICES                         | Collector-emitter cut-off |   | Tj = 25°C    | —    |        | 1    | mA   |
| 1020                         | current                   | VCE = VCES  | Tj = 125°C   | —    | _      | 10   |      |

### **CONTROL (PROTECTION) PART**

| Symbol   | Parameter                    |   | Condition            |               | Limits |      |      | Unit |
|----------|------------------------------|---|----------------------|---------------|--------|------|------|------|
| Symbol   | Farameter                    |   | Condition            |               | Min.   | Тур. | Max. | Unit |
|          |                              | VD = VDB = 15V                                      | Total of VP1-VPC, VN | I-VNC         |        | —    | 3.70 | mA   |
| ID       | Circuit current              | VIN = 5V  | VUFB-VUFS, VVFB-VV   | FS, VWFB-VWFS |        | —    | 1.30 | mA   |
| ID       |                              | VD = VDB = 15V                                      | Total of VP1-VPC, VN | -VNC          | _      | _    | 3.50 | mA   |
|          |                              | VIN = 0V  | VUFB-VUFS, VVFB-VV   | FS, VWFB-VWFS | -      | _    | 1.30 | mA   |
| VFOH     | Fault output voltage         | Vsc = 0V, Fo circuit pull-up to 5V with $10k\Omega$ |                      | 4.9           | _      | _    | V    |      |
| VFOL     | Fault output voltage         | VSC = 1V, IFO = 1mA                                 |                      |               | _      | 1.10 | V    |      |
| VSC(ref) | Short circuit trip level     | T <sub>i</sub> = 25°C, VD = 15V (Note 4)            |                      | 0.43          | 0.48   | 0.53 | V    |      |
| lin      | Input current                | VIN = 5V  | VIN = 5V             |               | 0.7    | 1.5  | 2.0  | mA   |
| UVDBt    |                              |   | Trip level           |               | 10.0   |      | 12.0 | V    |
| UVDBr    | Supply circuit under-voltage | Ti ≤ 125°C  | Reset level          |               | 10.5   | _    | 12.5 | V    |
| UVDt     | protection                   | 1j≤125°C  | Trip level           |               | 10.3   | _    | 12.5 | V    |
| UVDr     | ]                            |   | Reset level          |               | 10.8   | _    | 13.0 | V    |
| tFO      | Fault output pulse width     | CFO = 22nF  |                      | (Note 5)      | 1.6    | 2.4  | _    | ms   |
| Vth(on)  | ON threshold voltage         | Applied between UP, VP, WP-VPC, UN, VN, WN-VNC      |                      | 2.0           | 3.0    | 4.2  | V    |      |
| Vth(off) | OFF threshold voltage        |   |                      | 0.8           | 1.4    | 2.0  | V    |      |

Note 4: Short circuit protection is functioning only at the low-arms. Please select the value of the external shunt resistor such that the SC trip-

Short clicult protection is functioning only at the low arms, include colour the value of the external clicult resolution and the colour and the co

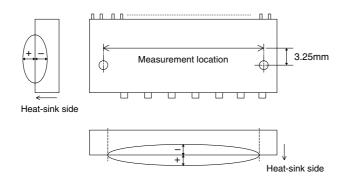


**TRANSFER-MOLD TYPE INSULATED TYPE** 

### MECHANICAL CHARACTERISTICS AND RATINGS

| Deremeter          | Can                                      | Limits    |      |    | Unit |      |
|--------------------|--|-----------|------|----|------|------|
| Parameter          | Con                                      | Condition |      |    | Max. | Unit |
| Mounting torque    | Mounting screw : M4 Recommended 1.18 N·m |           | 0.98 | —  | 1.47 | N∙m  |
| Weight             |  |           | —    | 77 | —    | g    |
| Heat-sink flatness | (Note 6)                                 |           | -50  | _  | 100  | μm   |

#### Note 6: Measurement point of heat-sink flatness



#### **RECOMMENDED OPERATION CONDITIONS**

| 0                           | Demonster                       | O and disting  |                |      | Limits |      | - Unit |
|-----------------------------|---------------------------------|--|----------------|------|--------|------|--------|
| Symbol                      | Parameter                       | Condition  |                | Min. | Тур.   | Max. |        |
| Vcc                         | Supply voltage                  | Applied between P-NU, NV, NW   |                | 350  | 600    | 800  | V      |
| Vd                          | Control supply voltage          | Applied between VP1-VPC, VN1-VNC   |                | 13.5 | 15.0   | 16.5 | V      |
| Vdb                         | Control supply voltage          | Applied between VUFB-VUFS, VVFB-VV   | /fs, Vwfb-Vwfs | 13.5 | 15.0   | 16.5 | V      |
| $\Delta V$ D, $\Delta V$ DB | Control supply variation        |  |                | -1   | _      | 1    | V/µs   |
| tdead                       | Arm shoot-through blocking time | For each input signal, Tc ≤ 100°C  |                | 3.3  | _      | _    | μs     |
| fpwm                        | PWM input frequency             | Tc ≤ 100°C, Tj ≤ 125°C   |                | —    | _      | 15   | kHz    |
| ю                           | Output r.m.s. current           | Vcc = 600V, VD = 15V, fc = 15kHz<br>P.F = 0.8, sinusoidal PWM<br>$T_i \le 125^{\circ}C$ , $T_C \le 100^{\circ}C$   | (Note 7)       | _    | _      | 1.8  | Arms   |
| PWIN(on)                    |                                 |  | (Note 8)       | 1.5  | _      | _    |        |
|                             | Minimum input pulse width       | $350 \le Vcc \le 800V,$<br>$13.5 \le VD \le 16.5V,$<br>$13.5 \le VDB \le 16.5V,$   | lc ≤ 5A        | 2.6  | _      | _    | μs     |
| PWIN(off)                   |                                 | $\label{eq:constraint} \begin{array}{ll} -20^\circ C \leq T c \leq 100^\circ C, \\ \mbox{N line wiring inductance less than} \\ 10 n \mbox{H} \mbox{(Note 9)} \end{array}$ | 5 < lc ≤ 8.5A  | 2.8  | _      | _    |        |
| VNC                         | VNC variation                   | Between VNC-NU, NV, NW (including  | surge)         | -5.0 | _      | 5.0  | V      |

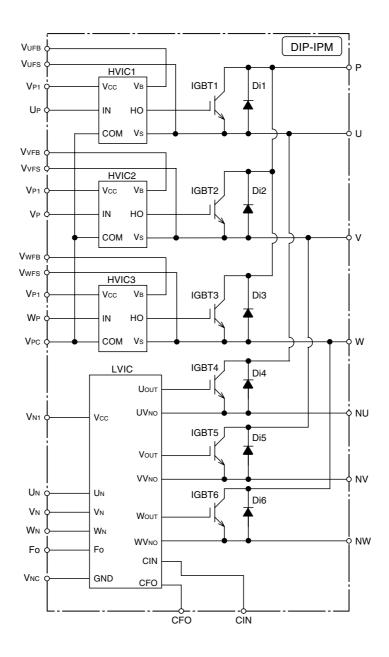
Note 7: The output r.m.s. current value depends on the actual application conditions.
 8: DIP-IPM might not make response to the input on signal with pulse width less than PWIN (on).
 9: DIP-IPM might not make response or work properly if the input off signal pulse width is less than PWIN (off).



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### Fig. 4 THE DIP-IPM INTERNAL CIRCUIT





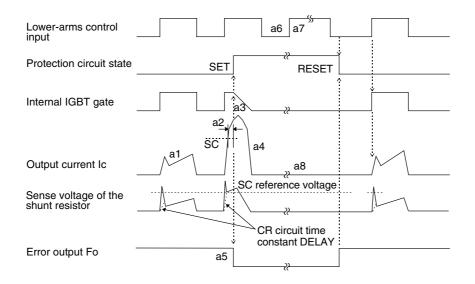
TRANSFER-MOLD TYPE INSULATED TYPE

### Fig. 5 TIMING CHARTS OF THE DIP-IPM PROTECTIVE FUNCTIONS

[A] Short-Circuit Protection (Lower-arms only with the external shunt resistor and CR filter)

- a1. Normal operation : IGBT ON and carrying current.
- a2. Short circuit current detection (SC trigger).
- a3. IGBT gate hard interruption.
- a4. IGBT turns OFF.
- a5. Fo output with a fixed pulse width determined by the external capacitor CFO.
- a6. Input = "L" : IGBT OFF
- a7. Input = "H" :

a8. IGBT OFF state in spite of input "H".

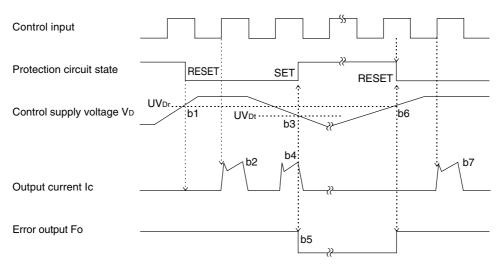


#### [B] Under-Voltage Protection (Lower-arm, UVD)

b1. Control supply voltage rising : After the voltage level reaches UVDr, the circuits start to operate when next input is applied.

b2. Normal operation : IGBT ON and carrying current.

- b3. Under voltage trip (UVDt).
- b4. IGBT OFF in spite of control input condition.
- b5. Fo keeps output during the UV period, however, Fo pulse is not less than the fixed width for very short UV interval.
- b6. Under voltage reset (UVDr).
- b7. Normal operation : IGBT ÓN and carrying current.

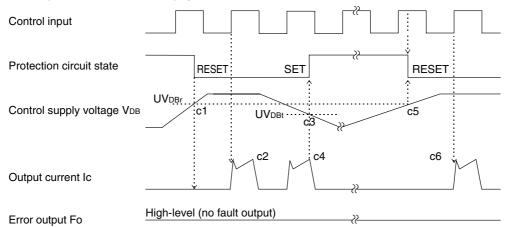




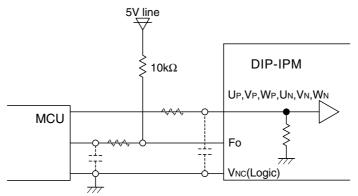
## **TRANSFER-MOLD TYPE INSULATED TYPE**

#### [C] Under-Voltage Protection (Upper-side, UVDB)

- c1. Control supply voltage rises : After the voltage reaches UVDBr, the circuits start to operate when next input is applied. c2. Normal operation : IGBT ON and carrying current.
- c3. Under voltage trip (UVDBt).
- c4. IGBT OFF in spite of control input signal level, but there is no Fo signal output.
- c5. Under voltage reset (UVDBr)
- c6. Normal operation : IGBT ON and carrying current.

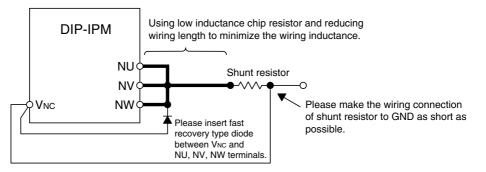


### Fig. 6 MCU I/O INTERFACE CIRCUIT



Note : RC coupling at each input (parts shown dotted) may change depending on the PWM control scheme used in the application and the wiring impedance of the application's printed circuit board. The DIP-IPM input signal section integrates a  $2.5 k\Omega$ (min) pull-down resistor. Therefore, when using a external filtering resistor, pay attention to the turn-on threshold voltage requirement.

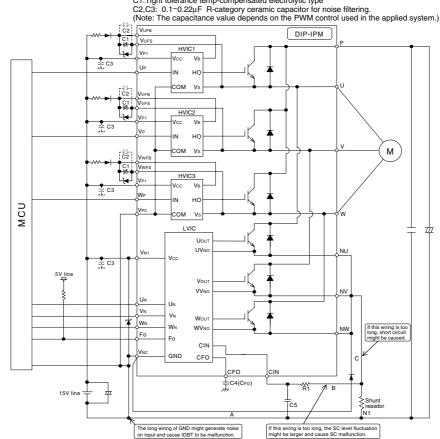
#### Fig. 7 WIRING CONNECTION WITH 1 SHUNT RESISTOR



For 3 shunt resistors connection, please refer to Fig.9.



### **TRANSFER-MOLD TYPE INSULATED TYPE**



#### Fig. 8 AN EXAMPLE OF TYPICAL DIP-IPM APPLICATION CIRCUT WITH 1 SHUNT RESISTOR C1:Tight tolerance temp-compensated electrolytic type

Note 1: To avoid malfunction, the wiring of each input should be as short as possible. (less than 2-3cm)
2: By virtue of integrating HVIC inside the module, direct coupling to MCU terminals without any opto-coupler or transformer isolation is possible.
3: Fo output is open drain type. The signal line should be pulled up to the positive side of a 5V supply with an approximate 10kΩ resistor.

- 4: Fo output pulse width (tFO) should be determined by connecting external capacitor C4 between CFO and VNC terminals. (Example :

- 4: Fo output pulse wight (tro) should be determined by connecting control supervise or external supervises or external sup wiring pattern.
- 8: All capacitors should be mounted as close to the terminals of the DIP-IPM as possible.
  9: To prevent surge destruction, the wiring between the smoothing capacitor and the P&N1 terminals should be as short as possible. Generally a 0.1~0.22µF snubber between the P&N1 terminals is recommended.
- 10: It is recommended to insert a Zener diode (24V/1W) between each pair of control supply terminals to prevent surge destruction.
- 11: To prevent LVIC from surge destruction, it is recommended to mount a fast recovery type diode between VNC and NU, NV, NW terminals.

#### Fig. 9 EXAMPLE OF EXTERNAL PROTECTION CIRCUIT WITH 3 SHUNT RESISTORS

